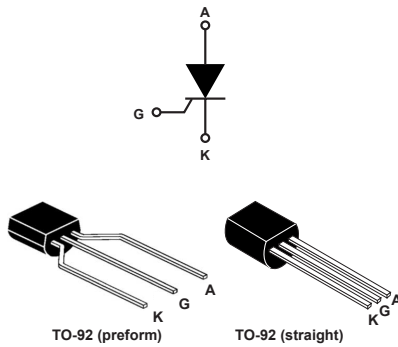


## 0.8 A 400 V high immunity sensitive SCR thyristor in TO-92



### Features

- On-state rms current,  $I_{T(RMS)}$  0.8 A
- 125 °C max.  $T_j$
- Low 0.2 mA gate current
- Repetitive peak off-state voltage,  $V_{DRM}/V_{RRM}$  400 V
- ECOPACK2 compliant

### Applications

- Gate driver for large Thyristors
- Overvoltage crowbar protection
- Ground fault circuit interrupters
- Arc fault circuit interrupter
- Standby mode power supplies
- Residual current detector

### Description

Thanks to highly sensitive triggering levels, the 0.8 A P0102DA SCR thyristor is suitable for all applications where available gate current is limited.

This device offers a high blocking voltage of 400 V, ideal for applications like interrupters circuits.

The P0102DA is available in through-hole TO-92 package.

#### Product status link

[P0102DA](#)

#### Product summary

|                   |        |
|-------------------|--------|
| $I_{T(RMS)}$      | 0.8 A  |
| $V_{DRM}/V_{RRM}$ | 400 V  |
| $I_{GT}$          | 0.2 mA |
| $T_{jmax.}$       | 125 °C |

# 1 Characteristics

**Table 1. Absolute maximum ratings (limiting values)**

| Symbol                              | Parameters                                                                                                  |                         |                         | Value       | Unit             |
|-------------------------------------|-------------------------------------------------------------------------------------------------------------|-------------------------|-------------------------|-------------|------------------|
| I <sub>T(RMS)</sub>                 | On-state RMS current (180° conduction angle)                                                                |                         | T <sub>L</sub> = 55 °C  | 0.8         | A                |
| I <sub>T(AV)</sub>                  | Average on-state current (180° conduction angle)                                                            |                         |                         | 0.5         | A                |
| I <sub>TSM</sub>                    | Non repetitive surge peak on-state current,                                                                 | t <sub>p</sub> = 8.3 ms | T <sub>j</sub> = 25 °C  | 8           | A                |
|                                     | T <sub>j</sub> initial = 25 °C                                                                              | t <sub>p</sub> = 10 ms  |                         | 7           |                  |
| I <sup>2</sup> t                    | I <sup>2</sup> t value for fusing                                                                           | t <sub>p</sub> = 10 ms  | T <sub>j</sub> = 25 °C  | 0.24        | A <sup>2</sup> s |
| di/dt                               | Critical rate of rise of on-state current<br>I <sub>G</sub> = 2 x I <sub>GT</sub> , t <sub>r</sub> ≤ 100 ns | F = 60 Hz               | T <sub>j</sub> = 25 °C  | 50          | A/μs             |
| V <sub>DRM</sub> / V <sub>RRM</sub> | Repetitive peak off-state voltage                                                                           |                         | T <sub>j</sub> = 125 °C | 400         | V                |
| I <sub>GM</sub>                     | Peak gate current                                                                                           | t <sub>p</sub> = 20 μs  | T <sub>j</sub> = 125 °C | 1           | A                |
| P <sub>G(AV)</sub>                  | Average gate power dissipation                                                                              |                         | T <sub>j</sub> = 125 °C | 0.1         | W                |
| T <sub>stg</sub>                    | Storage junction temperature range                                                                          |                         |                         | -40 to +150 | °C               |
| T <sub>j</sub>                      | Operating junction temperature range                                                                        |                         |                         | -40 to +125 | °C               |

**Table 2. Electrical characteristics ( $T_j = 25\text{ °C}$ , unless otherwise specified)**

| Symbol   | Parameters                                                                                         |      | Value | Unit       |
|----------|----------------------------------------------------------------------------------------------------|------|-------|------------|
| $I_{GT}$ | $V_D = 12\text{ V}$ , $R_L = 33\text{ }\Omega$                                                     | Max. | 200   | $\mu$ A    |
| $V_{GT}$ |                                                                                                    | Max. | 0.8   | V          |
| $V_{GD}$ | $V_D = V_{DRM}$ , $R_L = 3.3\text{ k}\Omega$ , $R_{GK} = 1\text{ k}\Omega$ , $T_j = 125\text{ °C}$ | Min. | 0.1   | V          |
| $V_{RG}$ | $I_{RG} = 10\text{ }\mu$ A                                                                         | Min. | 8     |            |
| $I_H$    | $I_T = 50\text{ mA}$ , $R_{GK} = 1\text{ k}\Omega$                                                 | Max. | 5     | mA         |
| $I_L$    | $I_G = 1.2 I_{GT}$ , $R_{GK} = 1\text{ k}\Omega$                                                   | Max. | 6     | mA         |
| $dV/dt$  | $V_D = 67\% V_{DRM}$ , $R_{GK} = 1\text{ k}\Omega$ , $T_j = 125\text{ °C}$                         | Min. | 75    | V/ $\mu$ s |

**Table 3. Static electrical characteristics**

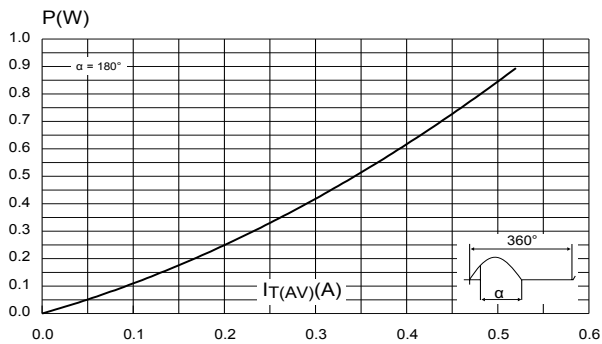
| Symbol    | Test conditions                                    | $T_j$  |      | Value | Unit       |
|-----------|----------------------------------------------------|--------|------|-------|------------|
| $V_T$     | $I_{TM} = 1.6\text{ A}$ , $t_p = 380\text{ }\mu$ s | 25 °C  | Max. | 1.95  | V          |
| $V_{TO}$  | Threshold on-state voltage                         | 125 °C | Max. | 0.95  | V          |
| $R_d$     | Dynamic resistance                                 | 125 °C | Max. | 600   | m $\Omega$ |
| $I_{DRM}$ | $V_D = V_{DRM}$                                    | 25 °C  | Max. | 1     | $\mu$ A    |
| $I_{RRM}$ | $V_R = V_{RRM}$                                    | 125 °C |      | 0.1   | mA         |

**Table 4. Thermal resistance**

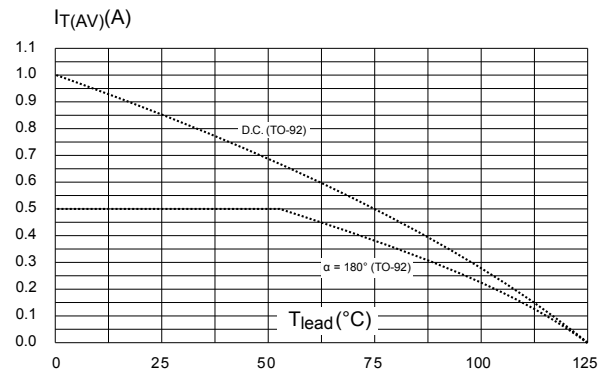
| Symbol        | Parameters               | Max. value | Unit |
|---------------|--------------------------|------------|------|
| $R_{th(j-l)}$ | Junction to lead (DC)    | 80         | °C/W |
| $R_{th(j-a)}$ | Junction to ambient (DC) | 150        |      |

## 1.1 Characteristics (curves)

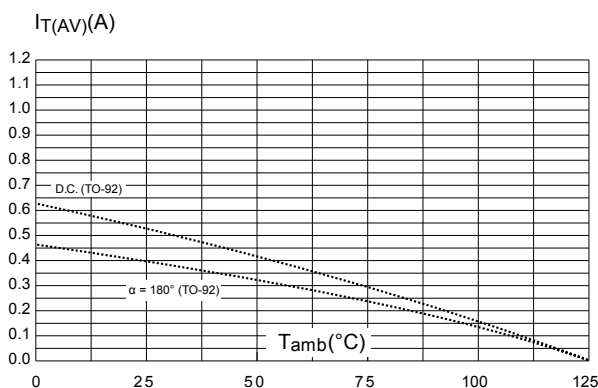
**Figure 1. Maximum power dissipation versus on-state RMS current (full cycle)**



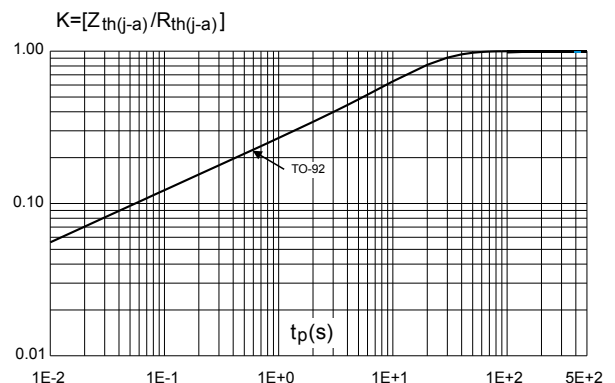
**Figure 2. Average and DC on-state current versus lead temperature**



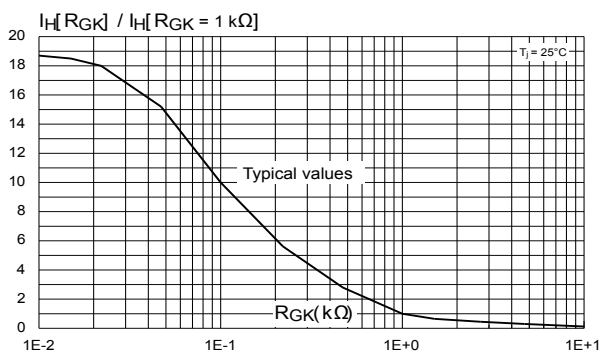
**Figure 3. Average and DC on-state current versus ambient temperature**



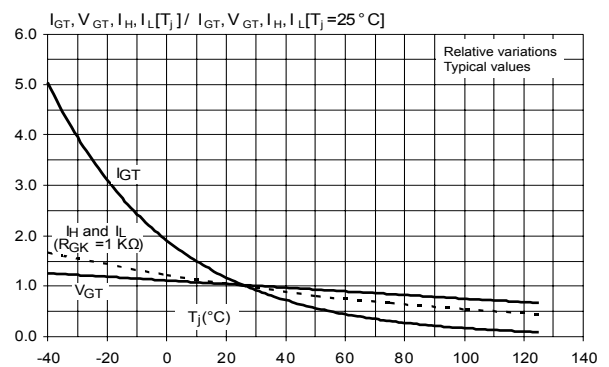
**Figure 4. Relative variation of thermal impedance versus pulse duration**



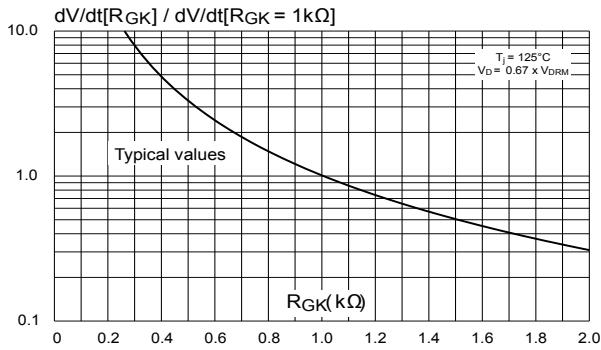
**Figure 5. Relative variation of holding current versus gate-cathode resistance**



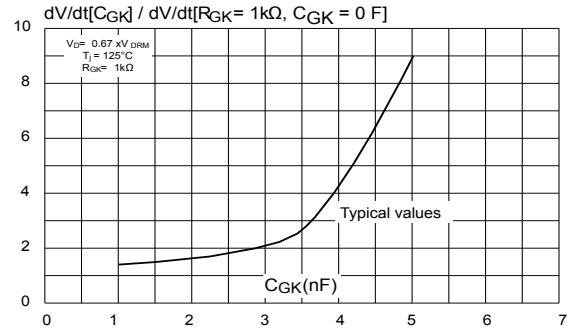
**Figure 6. Relative variation of gate voltage and gate, holding and latching current versus junction temperature**



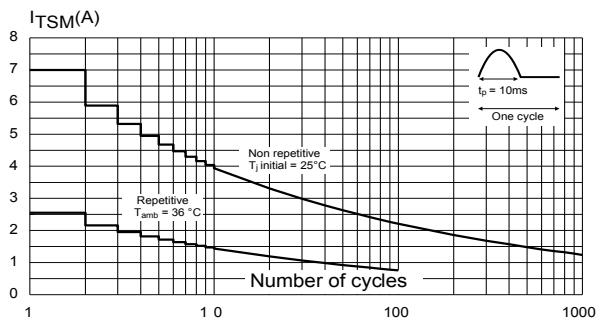
**Figure 7. Relative variation of static dV/dt immunity versus gate-cathode resistance**



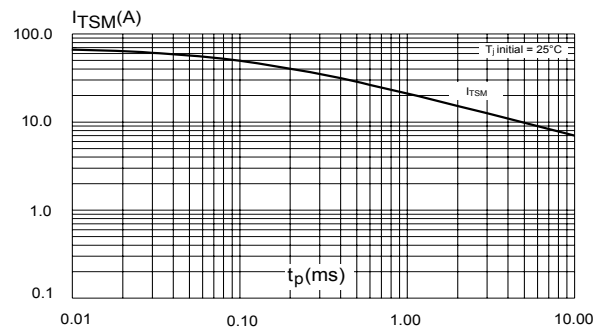
**Figure 8. Relative variation of dV/dt immunity versus gate-cathode capacitance**



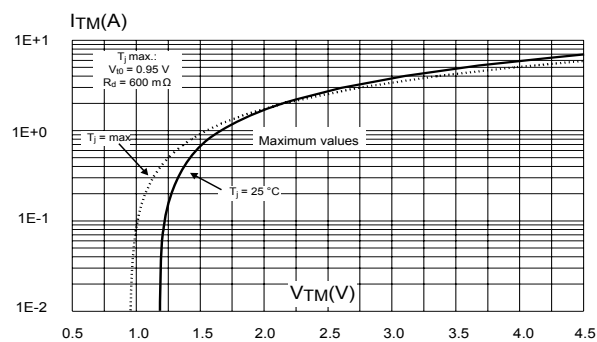
**Figure 9. Surge peak on-state current versus number of cycles**



**Figure 10. Non-repetitive surge peak on-state current for sinusoidal pulse ( $t_p < 10\text{ ms}$ )**



**Figure 11. On-state characteristics (maximum values)**



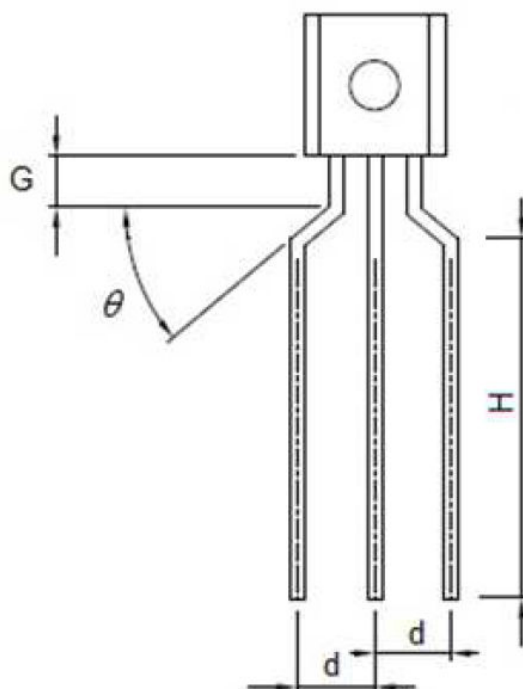
## 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

### 2.1 TO-92 with leads preform (plastic) package information

- Lead free plating + halogen-free molding resin
- Epoxy meets UL94, V0

**Figure 12.** TO-92 with leads preform (plastic) package outline



**Table 5.** TO-92 with leads preform (plastic) package mechanical data

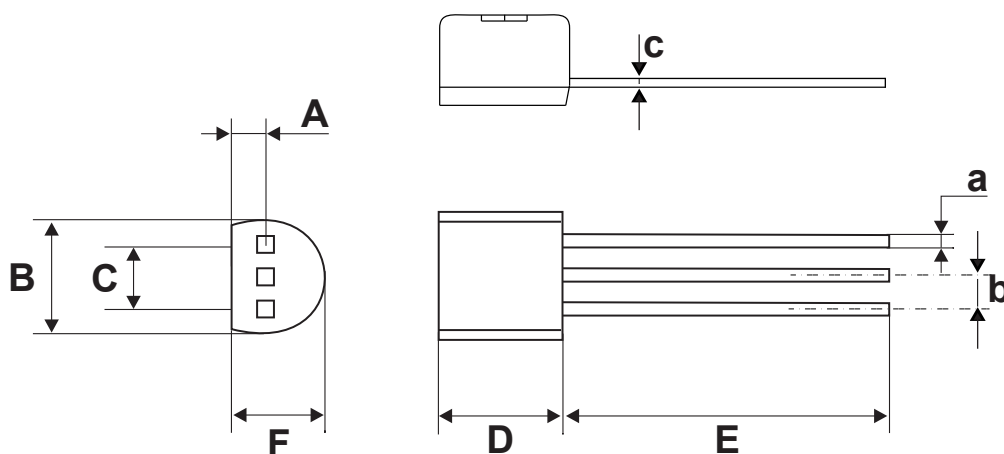
| Ref. | Dimensions  |      |      |                       |       |       |
|------|-------------|------|------|-----------------------|-------|-------|
|      | Millimeters |      |      | Inches <sup>(1)</sup> |       |       |
|      | Min.        | Typ. | Max. | Min.                  | Typ.  | Max.  |
| G    | 1.30        | 1.70 | 2.00 | 0.051                 | 0.067 | 0.079 |
| H    | 7.69        |      | 9.69 | 0.303                 |       | 0.381 |
| d    | 2.40        |      | 2.90 | 0.094                 |       | 0.114 |
| θ    | 30°         | 40°  | 50°  | 30°                   | 40°   | 50°   |

1. Inches dimensions given for information

## 2.2 TO-92 with straight leads (plastic) package information

- Lead free plating + halogen-free molding resin
- Epoxy meets UL94, V0

**Figure 13.** TO-92 with straight leads (plastic) package outline



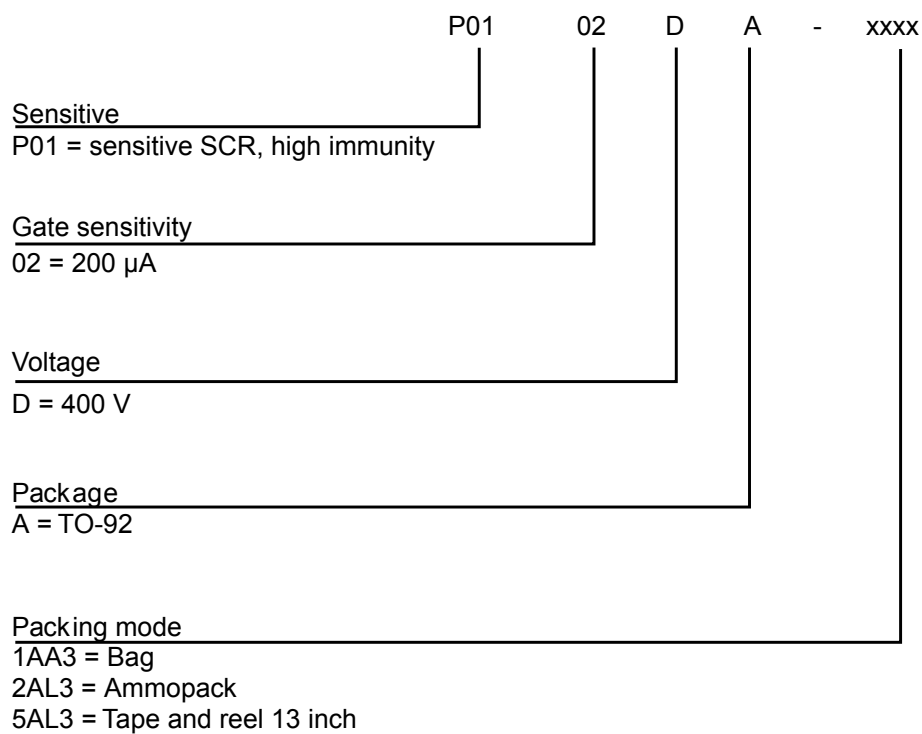
**Table 6.** TO-92 with straight leads (plastic) package mechanical data

| Ref. | Dimensions  |      |      |                       |       |       |
|------|-------------|------|------|-----------------------|-------|-------|
|      | Millimeters |      |      | Inches <sup>(1)</sup> |       |       |
|      | Min.        | Typ. | Max. | Min.                  | Typ.  | Max.  |
| A    |             | 1.35 |      |                       | 0.048 |       |
| B    |             |      | 4.70 |                       |       | 0.190 |
| C    |             | 2.54 |      |                       | 0.100 |       |
| D    | 4.40        |      |      | 0.172                 |       |       |
| E    | 12.70       |      |      | 0.554                 |       |       |
| F    |             |      | 3.70 |                       |       | 0.152 |
| a    |             |      | 0.50 |                       |       | 0.022 |
| b    |             | 1.27 |      |                       | 0.050 |       |
| c    |             |      | 0.48 |                       |       | 0.019 |

1. Inches dimensions given for information

### 3 Ordering information

**Figure 14. Ordering information scheme**



**Table 7. Ordering information**

| Order code   | Marking  | Package               | Weight | Base qty. | Delivery mode           |
|--------------|----------|-----------------------|--------|-----------|-------------------------|
| P0102DA 1AA3 | P0102 DA | TO-92 Straight Leads  | 0.22 g | 2500      | Bag                     |
| P0102DA 2AL3 |          | TO-92 Preformed Leads |        | 2000      | AMMOPACK not in dry bag |
| P0102DA 5AL3 |          | TO-92 Preformed Leads |        | 2000      | Tape and reel 13"       |

## Revision history

**Table 8. Document revision history**

| Date        | Revision | Changes                                                                                |
|-------------|----------|----------------------------------------------------------------------------------------|
| 14-Oct-2019 | 1        | Initial release.                                                                       |
| 18-May-2020 | 2        | Updated <i>Cover image</i> .                                                           |
| 03-Apr-2024 | 3        | Updated <a href="#">Section 2: Package information</a> , and <a href="#">Table 7</a> . |

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